

DECLARATION	AND POWER OF ATTO	RNEY - ORIGINAL	. APPLICATION	Attorney's Doci 202-0405	cet No.
Av residence, post	inventor, I hereby declar office address and citize	enship are as stated be	elow next to my name;	ess of the cubiant matter	r that is claims
and for which a pat	the original, first and so ent is sought on the inve	ention ended			T HIGH TO CHANNE
METHOD AND SY	STEM FOR RAPID HEA	TING OF AN EMISSIC	on control device		
he specification of	which is attached hereto	o.			
have reviewed an	d understand the conter	nts of the specification	identified above, includ	ding the claims.	P 49 . — 1-
accordance with Seas to application for the prior to this application for the prior to the application for the prior to the application for the ap	duty to disclose informat ection I.56(a), Title 37 of or patents or inventor's co ation by me or my legal r	ertificate on the inventi epresentatives or assig	on filed in any country	e examination of this at	tates of Ameri
[ X ]	no such applications hav	es been filed, or		•	
()	such applications have b	een filed as follows:			
[] (	hereby claim the benefi	t under 35 U.S.C. 119(	(e) of any United States	s provisional application	
COUNTRY	APPLICATION NO.	DATE OF FILING (month, day, year)	DATE OF ISSUE (month, day, year)	PRIORITY CLAIMED UNDER 35 USC 119	Additional provisional application numbers are on a suppler
					priority data PTO/SB/02f attached he
I hereby claim the	benefit under 35 U.S.C.	§ 120 of any United S	States application(s) or	§ 365(c) of any PCT in	iternational softhis applic
application design	benefit under 35 U.S.C. lating the United States, the prior United States knowledge the duty to d between the filing date	or PCT International a	pplication in the manne ich is material to paten and the national or PC	er provided by the first particular in 37 international filing di	paragraph of 3 7 CFR § 1.56 vate of this
(Application Number)		(Filing Date) (Status		- patented, pending, abandoned)	
(Application Number)		(		s - patented, pending, abandoned)	
POWER OF ATT prosecute the ap foreign Patent Of	ORNEY: - I/we hereby plication identified above fices.	appoint Practitioners a e, and to transact all bu	at Customer No. 02284 usiness in the United S	4, as my/our attorney(s tates Patent and Trade	i) or agent(s) t mark Office a

Attorney Docket No: 202-0405 Please call 313-322-7725 if this paper becomes separated from the file.





## Address all correspondence and telephone calls to:

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I hereby declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code, and that such willful false statements jeopardize the validity of the application or any patent issuing thereon.

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